

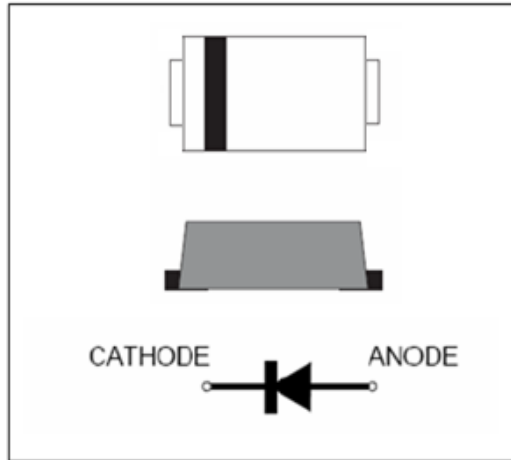
EFMAF101 thru EFMAF108

Surface Mount Glass Passivated Super Fast Rectifiers

Reverse Voltage 50 to 600V Forward Current 1.0A

FEATURES

- * Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- * High temperature metallurgically bonded construction
- * For use in high frequency rectifier circuits
- * Fast switching for high efficiency
- * Cavity-free glass passivated junction
- * Capable of meeting environmental standards of MIL-S-19500
- * 1.0 A operation at TC=75°C with no thermal runaway
- * Typical IR less than 1.0μA
- * High temperature soldering guaranteed: 260°C/10 seconds



We declare that the material of product is Halogen free (green epoxy compound)

2.Mechanical Data

Case: JEDEC SMA-FL, molded plastic over glass body

Terminals: Plated leads, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.0327 g

Handling precaution: None

Electrical Characteristic

1.Maximum & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter Symbol	symbol	EFMAF 101	EFMAF 102	EFMAF 103	EFMAF 104	EFMAF 105	EFMAF 106	EFMAF 107	EFMAF 108	Unit
Device marking code		EF1	EF2	EF3	EF4	EF5	EF6	EF7	EF8	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current at $T_C = 75^\circ\text{C}$	$I_F(AV)$	1.0								A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30								A
Typical thermal resistance (Note 2)	$R\theta_{JA}$ $R\theta_{JC}$	150 25								$^\circ\text{C/W}$
Operating junction and storage temperature range	T_J, T_{STG}	-50 to +150								$^\circ\text{C}$

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter Symbol	symbol	EFMAF 101	EFMAF 102	EFMAF 103	EFMAF 104	EFMAF 105	EFMAF 106	EFMAF 107	EFMAF 108	Unit	
Maximum instantaneous forward voltage at 1.0A	V_F	0.95			1.25		1.7			V	
Maximum DC reverse current $T_J = 25^\circ\text{C}$ at rated DC blocking voltage $T_J = 125^\circ\text{C}$	IR	5.0					100				μA
Typical reverse recovery time (Note 1)	t_{rr}	35									ns
Typical junction capacitance at 4.0V, 1MHz	CJ	15.0									PF

NOTES:

1. $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $IRR = 0.25\text{A}$
2. 8.0mm² (.013mm thick) land areas
3. V_F & TRR & V_{DC} & I_R all test; other parameter is scheme out.

EFMAF101 thru EFMAF108

2. Ratings and Characteristic Curves (TA = 25°C unless otherwise noted)

Fig. 1 - Forward Current Derating Curve

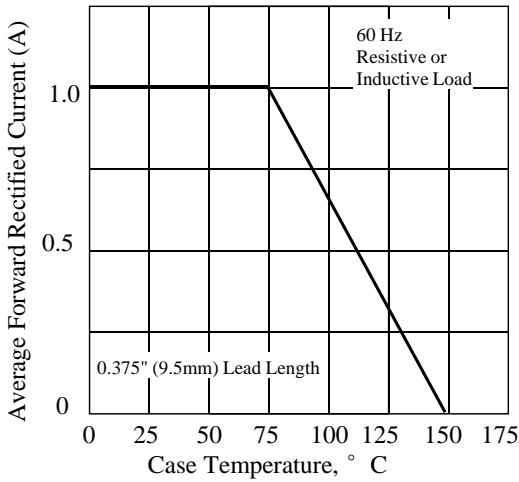


Fig. 2 - Maximum Non-repetitive Peak Forward Surge Current

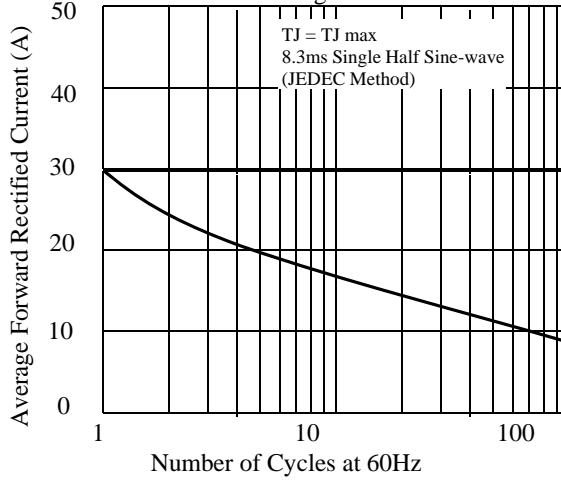


Fig 3. - Typical Instantaneous Forward Characteristics

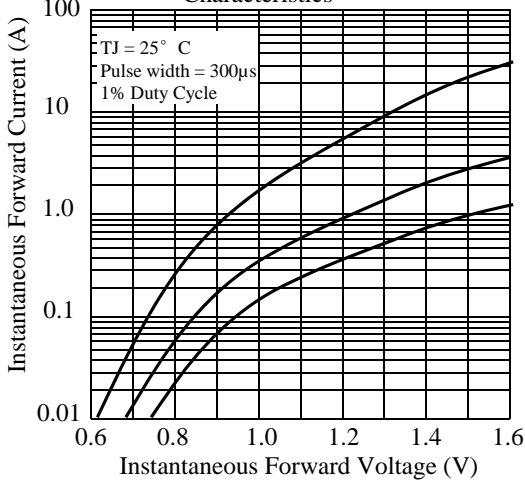


Fig 4. - Typical Reverse Characteristics

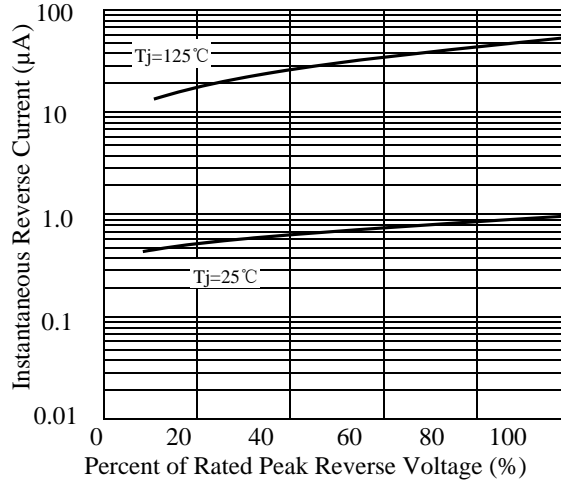


Fig 5. - typical transient thermal impedance

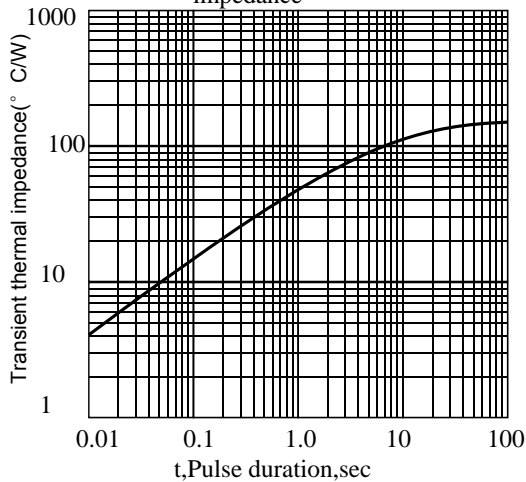
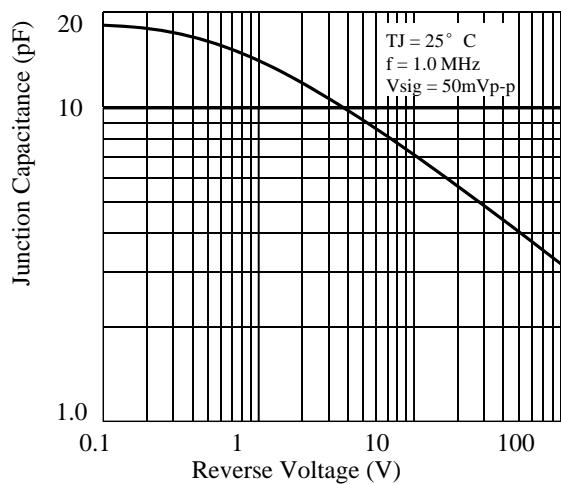
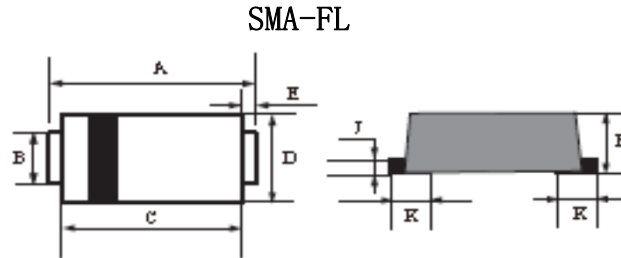


Fig 6. - Typical Junction Capacitance



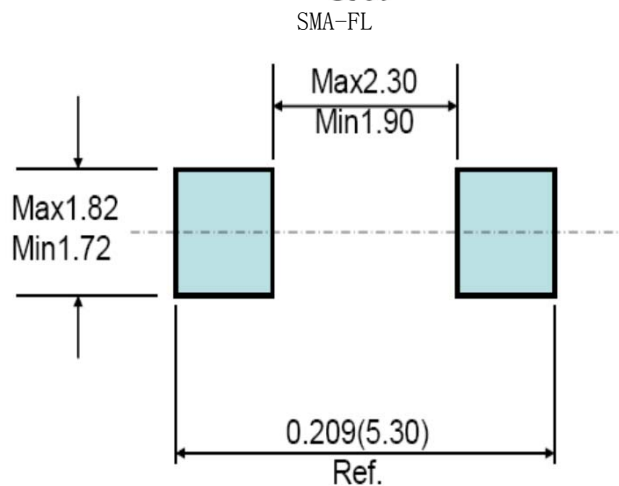
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3. dimension:



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.4	4.8	0.173	0.189
B	1.3	1.5	0.051	0.059
C	3.3	3.7	0.130	0.146
D	2.3	2.7	0.091	0.106
K	0.7	1.1	0.028	0.043
E	0.45	0.65	0.018	0.026
H	0.9	1.1	0.035	0.043
J	0.11	0.21	0.004	0.008

Mounting Pad Layout



EFMAF108-SH: EF---超快速二极管; M---SM贴片产品; AF---SMA-FL封装; 1---IF=1A; 08---VB=600V;

EFMAF101 thru EFMAF108

4. Update Record

版次	更新记录	更新作者	更新日期
1	第一版	周杰	2014. 04. 24
2	增加K尺寸	周杰	2015. 12. 30
3	修改IR高温条件	谭志伟	2016. 9. 27

单击下面可查看定价，库存，交付和生命周期等信息

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